Technical Training

Adlsong

SMPS Topologies

The Buck Converter









The voltage ripple of output capacitor: $i_L > I_o$, C_{out} is charged



2) The charge during the period

$$\Delta Q = \frac{1}{2} \frac{\Delta I_{Lpk}}{2} \frac{T_s}{2}$$

$$\Delta U_o = \frac{\Delta Q}{C_{out}} = \frac{(1-D)V_o}{8L_f C_{out} f_s^2}$$

Take ESR into Account: $\Delta U_o = ESR \bullet \Delta I_{Lpk} = \frac{(1-D)V_o \bullet ESR}{L_f f_S}$

Critical condition between DCM and CCM

$$I_o = \frac{1}{2} I_{L \max} = \frac{(V_{in} - V_o)D}{2L_f f_S}$$

DCM

$$I_o < \frac{1}{2} I_{L \max} = \frac{(V_{in} - V_o)D}{2L_f f_S}$$

$$T_{off} = D'T_{S} = \frac{(V_{in} - V_{o})D}{V_{o}}T_{S} < (1 - D)T_{S}$$

$$\overline{\frac{V_{o}}{V_{in}}} = \frac{D}{D + D'}$$



$$I_{o} = \frac{1}{2} I_{L \max} \frac{T_{on} + T_{off}}{T_{S}} = \frac{D^{2}}{2Lf_{S}} V_{in} \frac{V_{in} - V_{o}}{V_{o}}$$



2 The Boost Converter









The voltage ripple of output capacitor: $i_D > I_o$, C_{out} is charged



Take ESR into Account: $\Delta U_o = ESR \bullet \Delta I_{Lpk} = \frac{DV_{in} \bullet ESR}{L_f f_S}$

Critical condition between DCM and CCM



$$I_{in} = \frac{1}{2} I_{L \max} = \frac{V_{in} D}{2 L_f f_s}$$

$$I_{in} < \frac{1}{2} I_{L \max} = \frac{V_{in} D}{2 L_f f_s}$$

$$T_{off} = D'T_s = \frac{V_{in} D}{V_o - V_{in}} T_s < (1 - D)T_s$$

$$\frac{V_o}{V_{in}} = \frac{D + D'}{D'}$$



$$I_{o} = \frac{1}{2} I_{Lmax} \frac{T_{off}}{T_{S}} = \frac{D^{2}}{2Lf_{S}} \frac{V_{in}^{2}}{V_{o} - V_{in}}$$

Disadvantages: a limited power range a relatively high output ripple due to all of the off-time energy coming from the output capacitor

Advantages: simplicity, low cost and the ability to achieve up conversion without a transformer



Useful Power Level: 1 to 50 W Switch Voltage Stress: V_{out} Switch Power Stress: P_{in} Transformer Utilization: N/A Duty Cycle: <1.0 Output Ripple Frequency: f_s **Relative Cost: Low**

Rectifier:

$$V_{\rm RRM} > V_{\rm o} \qquad I_{\rm F(AV)} >$$

> I^

Power Switch: $V_{DDS} > V_o \qquad I_{Dmax} > I_o/(1-D) + \Delta I/2$

 $f_{S} = 1/T_{S} D = T_{ou}/T_{S} V_{o} = V_{iu}/(1-D)$

3 The Buck-Boost Converter









Critical condition between DCM and CCM



 I_{in}

$$in = \frac{1}{2} I_{L \max} = \frac{V_{in} D}{2 L_f f_S}$$

$$I_{in} < \frac{1}{2} I_{L \max} = \frac{V_{in} D}{2 L_f f_S}$$

$$I_{in} < \frac{1}{2} I_{L \max} = \frac{V_{in} D}{2 L_f f_S}$$

1

$$T_{off} = D'T_{S} = \frac{V_{in}D}{V_{o}}T_{S} < (1-D)T_{S}$$
$$\frac{V_{o}}{V_{in}} = \frac{D}{D'}$$



$$I_{o} = \frac{1}{2} I_{L \max} \frac{T_{off}}{T_{S}} = \frac{D^{2}}{2L f_{S}} \frac{V_{in}^{2}}{V_{o}}$$



Disadvantages: a limited power range a relatively high output ripple due to all of the off-time energy coming from the output capacitor

Advantages: simplicity, low cost and the ability to achieve negative conversion without a transformer



Useful Power Level: 1 to 50 W Switch Voltage Stress: V_{inmax} +V_{out} Switch Power Stress: P_{in} Transformer Utilization: N/A Duty Cycle: <1.0 Output Ripple Frequency: f_s **Relative Cost: Low**

Rectifier:

 $V_{RRM} > V_{inmax} + V_o \qquad I_{F(AV)} > I_o$

Power Switch:

$$V_{DDS} > V_{inmax} + V_o$$
 $I_{Dmax} > I_o/(1-D) + \Delta I/2$

 $f_{S} = 1/T_{S} D = T_{on}/T_{S} V_{o} = V_{in}/(1-D)$

Conclusion

	STEP DOWN	STEP UP	STEP UP/DOWN		
V _{out}	V _{in} . δ	V _{in} /1- δ	[-V _{in} .δ] / [1-δ]		
RMS current in C _{out}	low	high	high		
Supplied input current	discontinuous	continuous	discontinuous		
Gate drive	floating	grounded	floating		

3 The Fly Back Converter





Volt-Second Balance

The net change in energy in the transformer must be zero over one cycle.



The volt-seconds across the primary during turn on must equal that across the secondary during turn off, reflected to the primary.



$$(V_{in}-V_{DSS})T_{on} = V_{fl}T_{off}$$

$$V_{fl} = nV_o$$
$$n = N_p/N_s$$
$$V_{DSS} = 0$$

Volt-Second Balance

The net change in energy in the inductor must be Zero (average voltage: 0) over one cycle.



The integral of voltage over time volt-seconds across the inductor during turn on must equal that across the secondary during turn off



$$V_{Lon}T_{on} = V_{Loff}T_{off}$$

The change in current ΔI must be constant: $L\Delta I=V \Delta t$



Reflected Voltage During Off Stage

The approximate voltage across the secondary winding reflected to the primary

$$V_{fl} = n(V_o + V_{FD})$$

= nV_o

 $n = N_p/N_s$ V_{FD} : the forward voltage drop across the freewheeling diode

The reflected voltage is dependent on turns ratio and output voltage



Operation Modes for constant frequency fly back converter ①CCM--continuous

②DCM--discontinuous

The variable frequency or the self oscillating fly back converter

Ring Choke Converter operates at Critical Discontinuous Converter







Power Switch: V_{DDS}>V_{inmax}+nV_o+leakage inductance

spike
$$I_{Dpeak} > \frac{2P_{in}}{D_{\max}V_{in\min}}$$

$$I_{Drms} > \frac{2P_{in}}{V_{in\min}} \sqrt{\frac{1}{3D_{\max}}}$$

Secondary rectifier: $V_{RRM} > V_o + V_{inmax}/n$

$$\square I_{Fpeak} > \frac{2P_o}{V_o(1 - D_{max})} \qquad I_{F(AV)} > \frac{P_o}{V_o}$$

Discontinuous mode						
ADVANTAGES	DISADVANTAGES					
-(Zero turn-on losses)for the power switch	-High peak currents in rectifiers and power switches					
- Good transient line/load response	-Large output ripple: Cout (disc.) 2000 (cont.)					
- Feedback loop (single pole) easy to stabilize						
- Recovery time rectifier not critical: current is zero well before reverse voltage is applied						



Power Switch: V_{DDS} > V_{inmax} + nV_{o} + leakage inductance spike

$$I_{Dpeak} > \frac{2P_{in}}{D_{max}V_{in\,min}(1+A)} \qquad I_{Drms} > \frac{2P_{in}}{V_{in\,min}} \sqrt{\frac{1+A+A^2}{3D_{max}}}$$

Secondary rectifier: $V_{RRM} > V_o + V_{inmax}/n$
$$I_{Fpeak} > \frac{2P_o}{V_o(1-D_{max})(1+A)} \qquad I_{F(AV)} > \frac{P_o}{V_o} \qquad A = \frac{I_{peak} - \Delta I}{I_{peak}} = \frac{I_{min}}{I_{peak}}$$





Advantages

DCM

①More rapid response
②No right half plane pole and easy to compensate for feedback
③A slow recovery secondary diode can be used

CCM

①Lower rating required due to lower peak current
②Lower transient output voltage
③Spike at turn off

Disadvantages

DCM

①High capacitor ripple current②High peak diode current③Higher mosfet current

CCM

①Needs bigger transformer
②Commutating the secondary diode can cause switching noise around the output diode and ring in the ransformer can give worse EMI results

Given the same current excursion ΔI , larger throughout power if provided by continuous mode

For the same output power, peak currents are higher during discontinuous mode



The energy stored in the primary winding during turn on is given by:

$$E_{\text{stored}} = L_p I_{ppk}^2/2$$

The throughout power going into the primary winding is:

 $\mathsf{P}_{\rm in} = \mathsf{L}_{\rm p} f(\mathsf{I}_{\rm pmax}^2 - \mathsf{I}_{\rm pmin}^2)/2$

The energy and power delivered by the secondary are:

$$E_{delivered} = L_s I_{spk}^2/2$$

$$P_{o} = L_{s} f(I_{smax}^{2} - I_{smin}^{2})/2$$

$$P_{in} = P_o, E_{stored} = E_{delivered}$$

Right Half Plane Zero



Right half plane zeroes in the characteristic equation {1 + G(s)H(s)} tends to destabilize the system.

Critically discontinuous operation

It is the transition point between DCM and CCM. With critically discontinuous mode of operation, primary winding current starts from zero at every cycle. Secondary current goes down to zero just when primary winding current starts ramping up again.

Off time + on time = fly back period

There is no idle period. Equation for DCM can apply for it.

Given a constant turn on period, output current is a function of turn off period. The rule of thumb for 50% duty cycle, you have to transfer twice th total output power within the on period.

Po = Lflpk2/2

For ¹/₄ the original power, frequency will double. At no load frequency will go very very high so a minimum and maximum load must be determined.







Design consideration

1 Effective leakage inductance and causes energy stored in leakage inductance

- 2 Short circuit current
- 3 Cross regulation
- 4 Diode voltage drops
- 5 Capacitor ripple voltage
- 6 Open loop fly back operation

Leakage is caused by the imperfect coupling between the primary and the secondary windings. It is not affected by changing the core material. Usually expressed as a percentage of winding inductance.



1 The fly back does not need a reset winding since the core is mad to de-saturate during turn off. The core is made to store all the input energy during turn on before it is allowed to deliver the energy to the load during turn off. a high power transformer is needed for the fly back than the forward converter.

2 To be able to store significant amount of energy in the core, an air gap is required since considerably more energy can be stored in the air gap than in the ferromagnetic part of the core.

3 Only one output can be directly regulated with other outputs acting as slaves. Multi-regulation will affect the regulation rate.

4 Feedback loop is easily stabilized with DCM. Vo/Vin= D/n(1-D), the term (1-D) in the denominator constitutes a Right Half Plane Zero and has a dramatic effect on the response of the circuit to sudden load changes, reducing gain slope by 20dB/decade but increasing phase lag by 90. The only way to stabilize the feedback loop during CCM is to drastically reduce the error amplifier bandwidth for reducing response time.





Unlike a forward transformer, the secondary winding of a fly back transformer has a polarity that of the primary winding. A forward transformer is a voltage transformer in the practical sense. The fly back transformer is effectively a current transformer

Fly Back advantages and disadvantages over Forward converter **Advantages:**

More than one output is possible on one supply Output voltage range highly

Simple design

Only one output diode needed and inductance no needed Voltage between primary and secondary is lower than for a forward

Disadvantages:

Generally less efficient

Leakage inductance energy needs to be dissipated in snubber, in forward the energy goes back to the source via the reset winding.

The fly back topology is one of the most common and cost-effective means of generating moderate levels of isolated power in AC/DC converters. Additional output voltages can be generated easily by adding additional secondary windings. There are some disadvantages. however. Regulation and output ripple are not as tightly controlled as in some of the other topologies and the stresses on the power switch are higher. Useful power level: 5 to 150 Watts Switch voltage stress: $V_{in} + (N_p/N_s) V_{out}$ Switch power stress: P_{in} Transformer utilization: Poor/specialized design Duty cycle: <0.5 Output ripple frequency: f_s Relative cost: Low-moderate



A double switch fly back converter

In the single switch fly back, an over voltage spike is applied across the power switch at each turn off. The peak value of this over voltage depends upon the switching time, the circuit capacitance and the primary to secondary transformer leakage inductance. So, a single switch fly back nearly always requires a snubber circuit limiting this voltage spike. In a double switch fly back, the leakage inductance of the power transformer is much less critical. The two demagnetization diodes D1 andD2 provide a single non dissipative way to systematically clamp the voltage across the switches to the input DC voltage Vin. This energy recovery system allows us to work at higher switching frequencies and with a better efficiency than that of the single switch structure. However, the double switch structure requires driving a high side switch. This double switch fly back is also known as asymmetrical half bridge fly back.



Power Switch: $V_{DDS} > V_{inmax}$

Primary Rectifier: $V_{RRM} > V_{inmax}$

Table 4. Estimating the Significant Parameters of the Power Semiconductors

	Bipolar Power Switch		MOSFET Power Switch		Rectifier(s)	
Topology	VCEO	Iс	VDSS	۱ _D	V _R	١ _F
Buck	Vin	lout	V _{in}	lout	Vin	lout
Boost	Vout	2.0 P _{out} Vin(min)	Vout	2.0P _{out} Vin(min)	Vout	lout
Buck/Boost	Vin – Vout	2.0 P _{out} Vin(min)	Vin – V _{out}	2.0 P _{out} Vin(min)	Vin – Vout	lout
Flyback	1.7 Vin(max)	2.0 P _{out} Vin(min)	1.5 Vin(max)	2.0P _{out} Vin(min)	10 Vout	lout
1 Transistor Forward	2.0 V _{in}	1.5P _{out} V _{in(min)}	2.0 V _{in}	1.5 P _{out} Vin(min)	3.0 V _{out}	lout
Push-Pull	2.0 V _{in}	1.2P _{out} V _{in(min)}	2.0 V _{in}	1.2P _{out} Vin(min)	2.0 V _{out}	lout
Half-Bridge	Vin	2.0 Pout Vin(min)	Vin	2.0 P _{out} Vin(min)	2.0 V _{out}	lout
Full-Bridge	Vin	1.2 P _{out} V _{in(min)}	Vin	1.2P _{out} Vin(min)	2.0 Vout	lout